

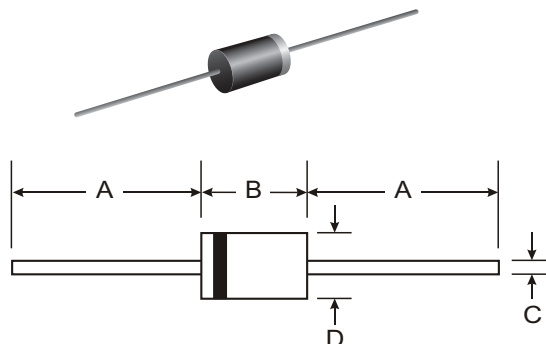
**VOLTAGE RANGE: 1000V**  
**CURRENT: 0.1A**

### Features

- Low leakage
- Low forward voltage drop
- High current capability
- Easily cleaned with Freon, Alcohol, Isopropanol and similar solvents
- The plastic material carries U/L recognition 94V-0

### Mechanical Data

- Case: DO-41, molded plastic
- Terminals: Axial lead, solderable per
- MIL-STD-202, Method 208
- Polarity: Color band denotes cathode
- Weight: 0.012 ounces, 0.34 grams
- Mounting position: Any



DO-41		
Dim	Min	Max
A	25.40	—
B	4.06	5.21
C	0.71	0.864
D	2.00	2.72
All Dimensions in mm		

### Maximum Ratings and Electrical Characteristics T<sub>A</sub> = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	ERA34-10	Unit
Maximum recurrent peak reverse voltage	V <sub>RRM</sub>	1000	V
Maximum RMS voltage	V <sub>RMS</sub>	700	V
Maximum DC blocking voltage	V <sub>DC</sub>	1000	V
Maximum average forward rectified current 9.5mm lead length, @T <sub>A</sub> =75°C	I <sub>F(AV)</sub>	0.1	A
Peak forward surge current 8.3ms single half-sine-wave superimposed on rated load @T <sub>J</sub> =125°C	I <sub>FSM</sub>	10.0	A
Maximum instantaneous forward voltage @ 0.1 A	V <sub>F</sub>	1.0	V
Maximum reverse current @T <sub>A</sub> =25°C at rated DC blocking voltage @T <sub>A</sub> =100°C	I <sub>R</sub>	5.0 100.0	μA
Maximum reverse recovery time (Note1)	t <sub>rr</sub>	150	ns
Typical junction capacitance (Note2)	C <sub>J</sub>	12	pF
Typical thermal resistance (Note3)	R <sub>θJA</sub>	55	°C/W
Operating junction temperature range	T <sub>J</sub>	-55----+150	°C
Storage temperature range	T <sub>STG</sub>	-55----+150	°C

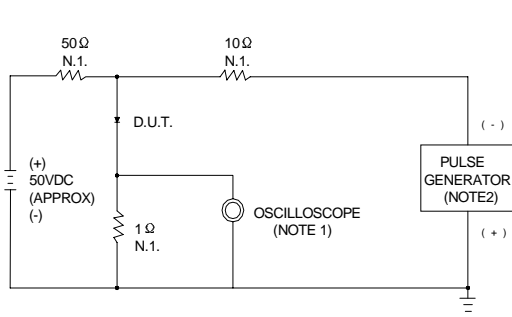
NOTE:1. Measured with I<sub>F</sub>=0.5A, I<sub>R</sub>=1A, I<sub>r</sub>=0.25A.

2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

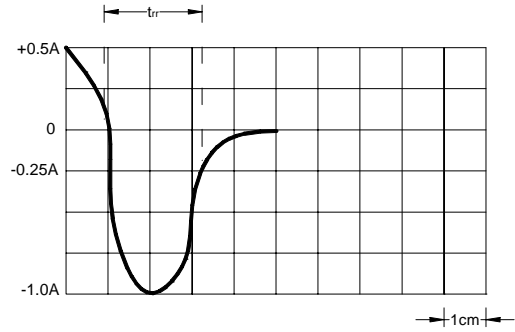
3. Thermal resistance from junction to ambient.



**FIG.1 – REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM**



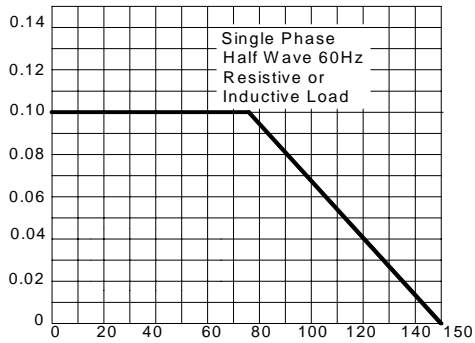
NOTES: 1. RISE TIME=7ns MAX. INPUT IMPEDANCE=1MΩ, 22pF  
 2. RISE TIME=10ns MAX. SOURCE IMPEDANCE=50Ω



SET TIMEBASE FOR 50/100 ns/cm

**FIG.2 – FORWARD DERATING CURVE**

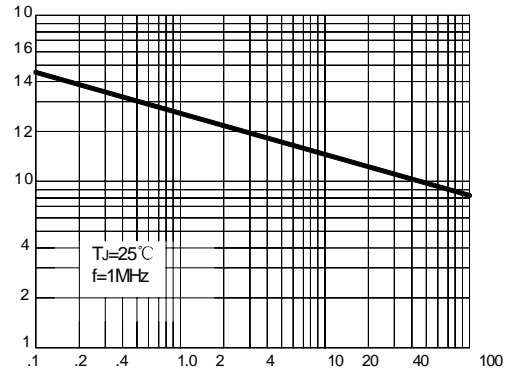
AVERAGE FORWARD CURRENT  
AMPERES



AMBIENT TEMPERATURE, °C

**FIG.3 – TYPICAL JUNCTION CAPACITANCE**

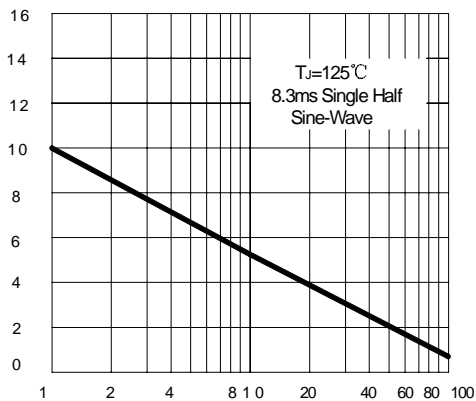
JUNCTION CAPACITANCE, pF



INSTANTANEOUS FORWARD VOLTAGE, VOLTS

**FIG.4 – PEAK FORWARD SURGE CURRENT**

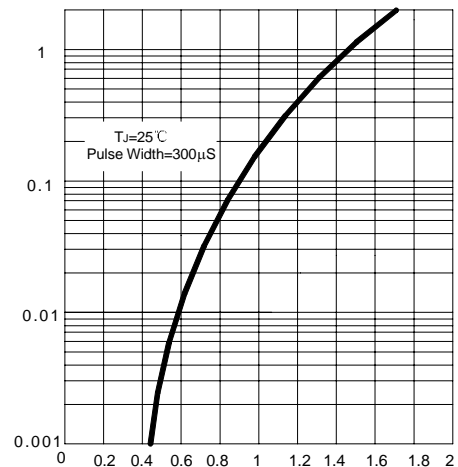
PEAK FORWARD SURGE CURRENT  
AMPERES



NUMBER OF CYCLES AT 60 Hz

**FIG.5 – TYPICAL FORWARD CHARACTERISTIC**

INSTANTANEOUS FORWARD CURRENT  
CURRENT AMPERES



INSTANTANEOUS FORWARD VOLTAGE, VOLTS